

## INDIAN INSTITUTE OF TECHNOLOGY TIRUPATI

## भारतीय प्रौद्योगिकी संस्थान तिरुपति

Yerpedu-Venkatagiri Road, Yerpedu Post, Tirupati District, Andhra Pradesh - 517 619

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1.	Title of the course	Semiconductor Devices
2.	Course number	EE210M
3.	Structure of credits (L-T-P-C)	3-1-0-4
4.	New course/modification to	Modified with EE202M/SOLID STATE DEVICES
5.	To be offered by	Electrical Engineering
6.	Prerequisite	None
7.	<b>Course Objective(s):</b> To analyze the electronic properties of semiconductors and discuss the fundamentals of semiconductor device physics. To explain the physics and operation of basic semiconductor devices employed in electronic circuits.	
8.	Course Content: Crystal structure, basics of quantum mechanics, formation of energy bands in solids, E-k diagram, effective mass, concept of hole, density of states, Fermi level; Carrier concentration: thermal equilibrium, equilibrium carrier concentration, excess carriers, quasi-Fermi levels, generation and recombination of carriers, carrier lifetime; Carrier transport: drift and diffusion, mobility, velocity saturation, diffusion length, continuity and Poisson's equations; Quantitative theory of PN junctions: equilibrium analysis, steady state I-V characteristics under forward bias, reverse bias and illumination, energy band diagram, capacitances, dynamic behavior under small and large signals, breakdown mechanisms; Bipolar Junction Transistor (BJT): physics and characteristics; Hetero junctions; Metal-semiconductor junctions: Schottky diode, Ohmic contact; Field Effect Transistor (FET): analysis of Metal Oxide Semiconductor (MOS) capacitor, calculation of threshold voltage, static I-V characteristics of Metal Oxide Semiconductor Field Effect Transistor (MOSFET) and their models; Light-matter interactions; Optoelectronic devices like photo detectors, solar cells and Light Emitting Diodes (LEDs).	
9.	Textbook(s):  1. Streetman B G and Banerjee S K, Solid State Electronic Devices, 7th Edition, Prentice Hall India (2014).  2. Pierret R, Semiconductor Device Fundamentals, Pearson Education (2006).	
10.	Reference(s): 1. Dimitrijev S, Principles of Semiconductor Devices, 2nd Edition, Oxford University Press (2012). 2. Neamen D A, Semiconductor Physics and Devices, 4th Edition, McGraw Hill Education (2012). 3. Sah C T, Fundamentals of Solid State Electronics, World Scientific (1991). 4. Tyagi M S, Introduction to Semiconductor Materials and Devices, John Wiley (2004).	